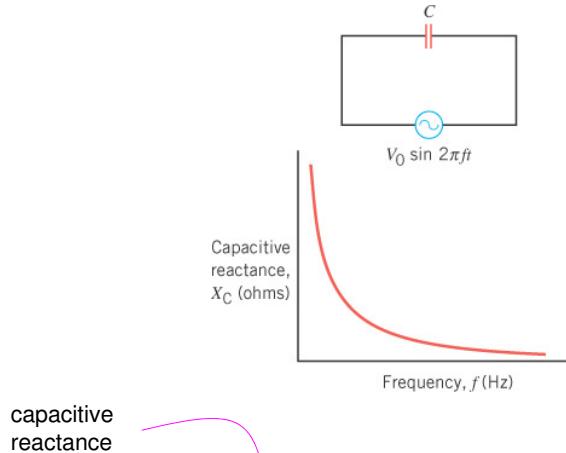


Chapter 23

Alternating Current Circuits

1

23.1 Capacitors and Capacitive Reactance

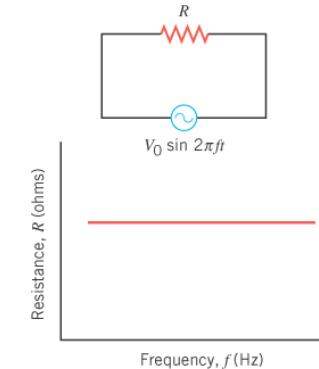


$$V_{\text{rms}} = I_{\text{rms}} X_C$$
$$X_C = \frac{1}{2\pi f C}$$

3

23.1 Capacitors and Capacitive Reactance

The resistance in a purely resistive circuit has the same value at all frequencies.



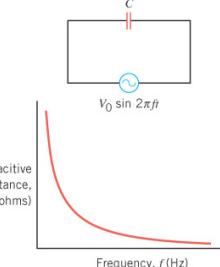
$$V_{\text{rms}} = I_{\text{rms}} R$$

2

23.1 Capacitors and Capacitive Reactance

Example 1 A Capacitor in an AC Circuit

The capacitance is $1.50\mu\text{F}$ and the rms voltage is 25.0 V. What is the rms current when the frequency is (a) 100 Hz and (b) 5000 Hz?



4

23.1 Capacitors and Capacitive Reactance

$$(a) X_C = \frac{1}{2\pi fC} = \frac{1}{2\pi(100 \text{ Hz})(1.50 \times 10^{-6} \text{ F})} = 1060 \Omega$$

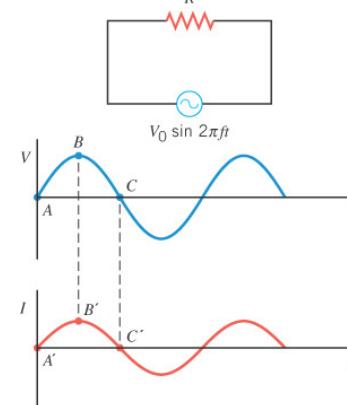
$$I_{\text{rms}} = \frac{V_{\text{rms}}}{X_C} = \frac{25.0 \text{ V}}{1060 \Omega} = 0.0236 \text{ A}$$

$$(b) X_C = \frac{1}{2\pi fC} = \frac{1}{2\pi(5000 \text{ Hz})(1.50 \times 10^{-6} \text{ F})} = 21.2 \Omega$$

$$I_{\text{rms}} = \frac{V_{\text{rms}}}{X_C} = \frac{25.0 \text{ V}}{21.2 \Omega} = 1.18 \text{ A}$$

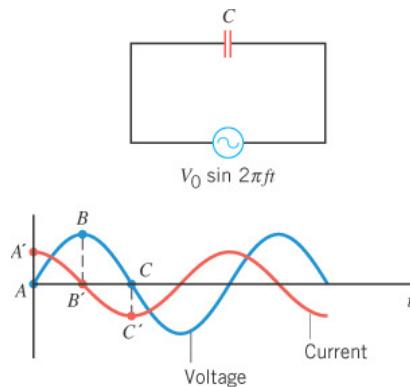
5

For a purely resistive circuit, the current and voltage are **in phase**.



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23.1 Capacitors and Capacitive Reactance

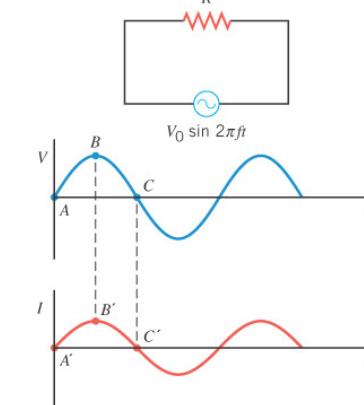


The current in a capacitor leads the voltage across the capacitor by a phase angle of 90 degrees.

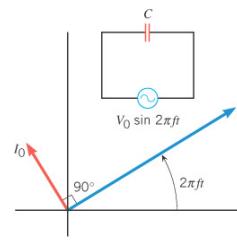
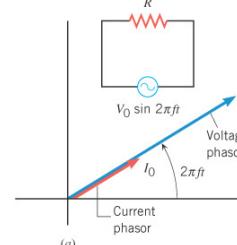
The average power used by a capacitor in an ac circuit is zero.

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23.1 Capacitors and Capacitive Reactance



23.1 Capacitors and Capacitive Reactance



In the **phasor** model, the voltage and current are represented by rotating arrows (called **phasors**).

These phasors rotate at a frequency f .

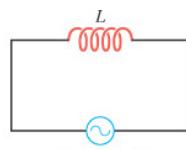
The vertical component of the phasor is the instantaneous value of the current or voltage.

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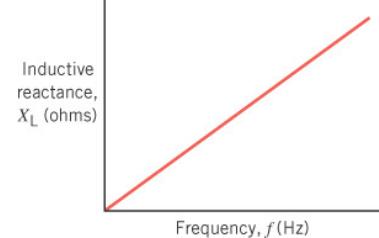
23.2 Inductors and Inductive Reactance

inductive reactance

$$V_{\text{rms}} = I_{\text{rms}} X_L$$



$$V_0 \sin 2\pi ft$$

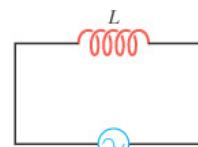


$$X_L = 2\pi f L$$

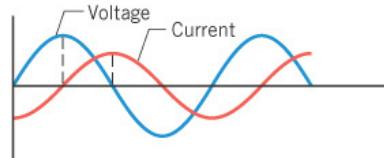
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23.2 Inductors and Inductive Reactance

The current **lags** behind the voltage by a phase angle of 90 degrees.



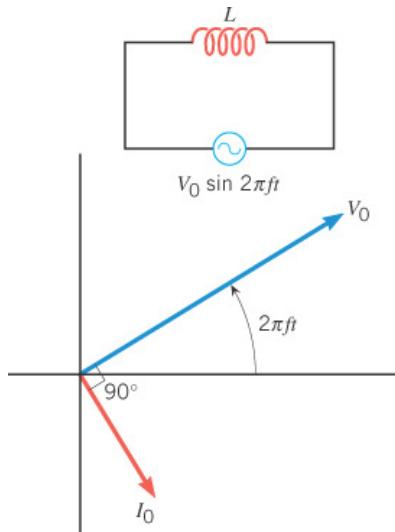
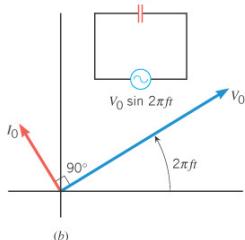
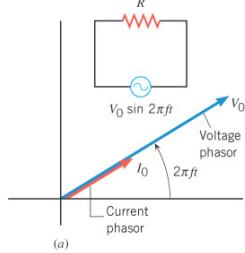
$$V_0 \sin 2\pi ft$$



The average power used by an inductor in an ac circuit is zero.

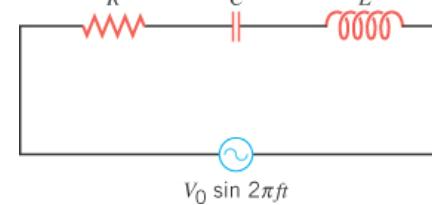
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23.2 Inductors and Inductive Reactance



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23.3 Circuits Containing Resistance, Capacitance, and Inductance



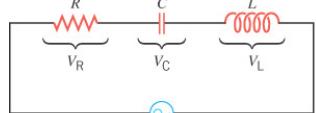
In a series RLC circuit, the total opposition to the flow is called the **impedance**.

$$V_{\text{rms}} = I_{\text{rms}} Z$$

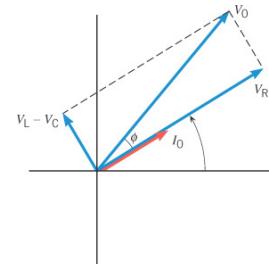
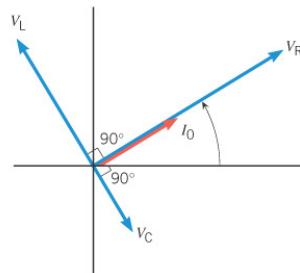
$$Z = \sqrt{R^2 + (X_L - X_C)^2}$$

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23.3 Circuits Containing Resistance, Capacitance, and Inductance

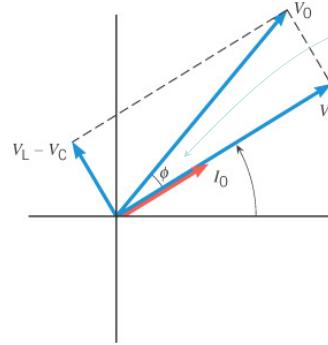


$$Z = \sqrt{R^2 + (X_L - X_C)^2}$$



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23.3 Circuits Containing Resistance, Capacitance, and Inductance



phase angle between current and total voltage

$$\tan \phi = \frac{V_L - V_C}{V_R} = \frac{X_L - X_C}{R}$$

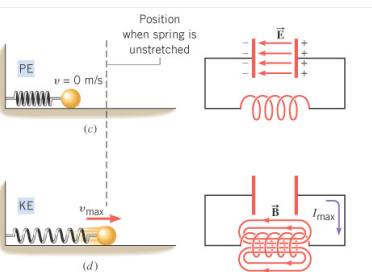
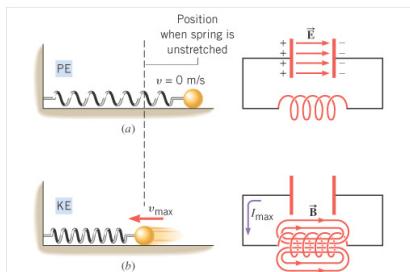
$$\bar{P} = I_{\text{rms}}^2 Z \cos \phi = I_{\text{rms}} V_{\text{rms}} \cos \phi$$

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23.4 Resonance in Electric Circuits

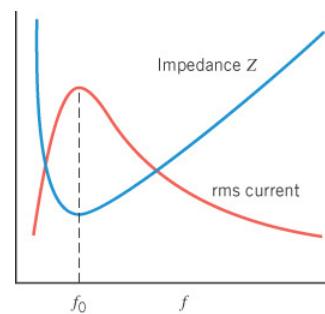
Resonance occurs when the frequency of a vibrating force exactly matches a natural (resonant) frequency of the object to which the force is applied.

The oscillation of a mass on a spring is analogous to the oscillation of the electric and magnetic fields that occur, respectively, in a capacitor and an inductor.



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23.4 Resonance in Electric Circuits



$$Z = \sqrt{R^2 + (2\pi f L - 1/(2\pi f C))^2}$$

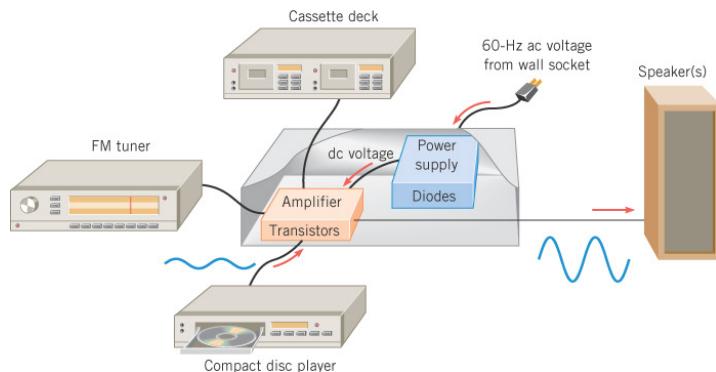
$$I_{\text{rms}} = \frac{V_{\text{rms}}}{\sqrt{R^2 + (2\pi f L - 1/(2\pi f C))^2}}$$

Resonant frequency $f_o = \frac{1}{2\pi\sqrt{LC}}$

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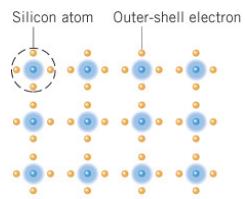
23.5 Semiconductor Devices

Semiconductor devices such as diodes and transistors are widely used in modern electronics.

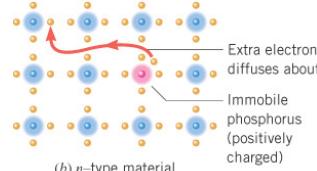


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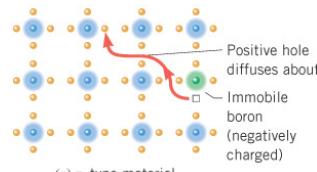
23.5 Semiconductor Devices



(a) Pure material



(b) n-type material



(c) p-type material

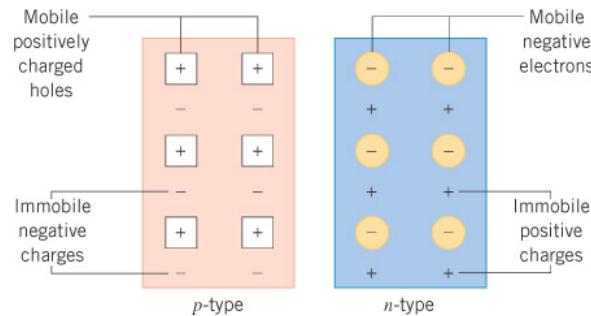
n-TYPE AND p-TYPE SEMICONDUCTORS

The semiconducting materials (silicon and germanium) used to make diodes and transistors are **doped** by adding small amounts of an impurity element.

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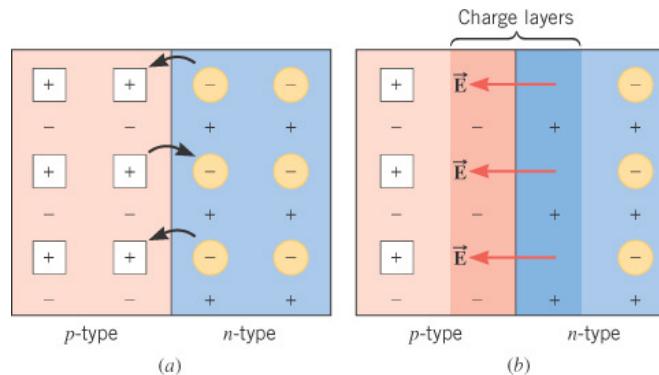
23.5 Semiconductor Devices

THE SEMICONDUCTOR DIODE



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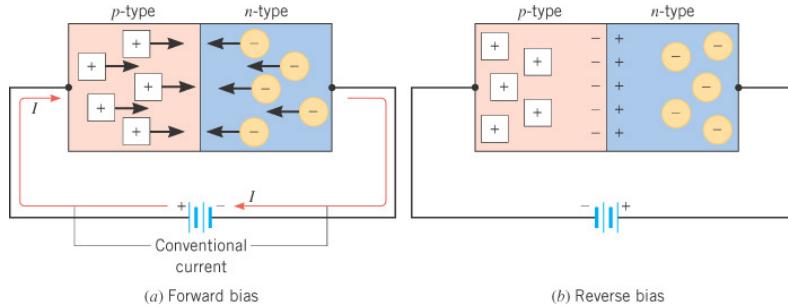
23.5 Semiconductor Devices



At the junction between the n and p materials, mobile electrons and holes combine and create positive and negative charge layers.

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23.5 Semiconductor Devices

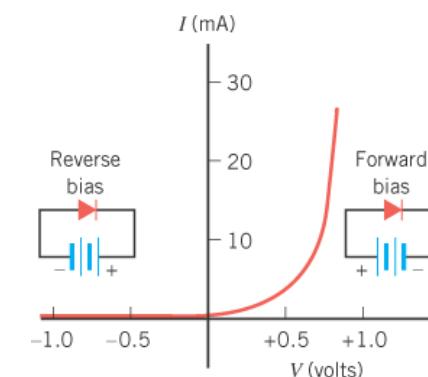


There is an appreciable current through the diode when the diode is forward biased.

Under a reverse bias, there is almost no current through the diode.

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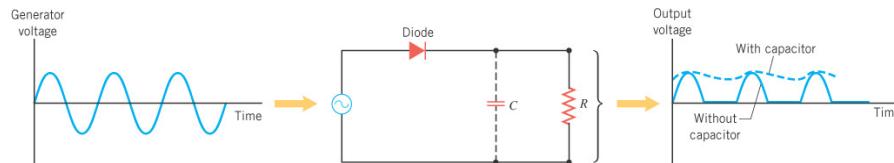
23.5 Semiconductor Devices



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23.5 Semiconductor Devices

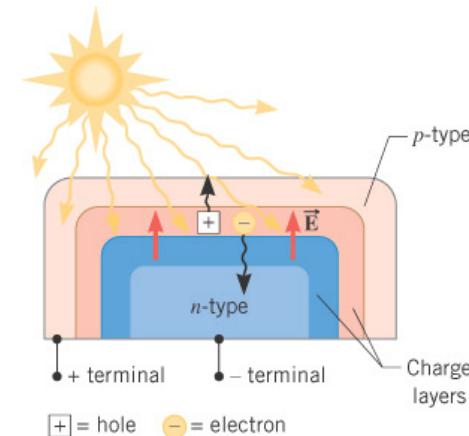
A half-wave rectifier.



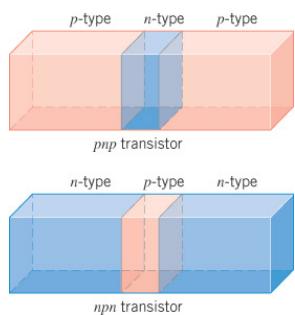
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23.5 Semiconductor Devices

SOLAR CELLS

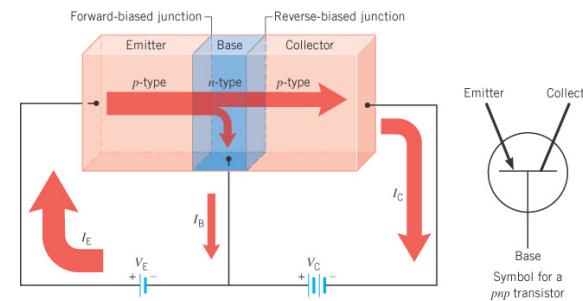


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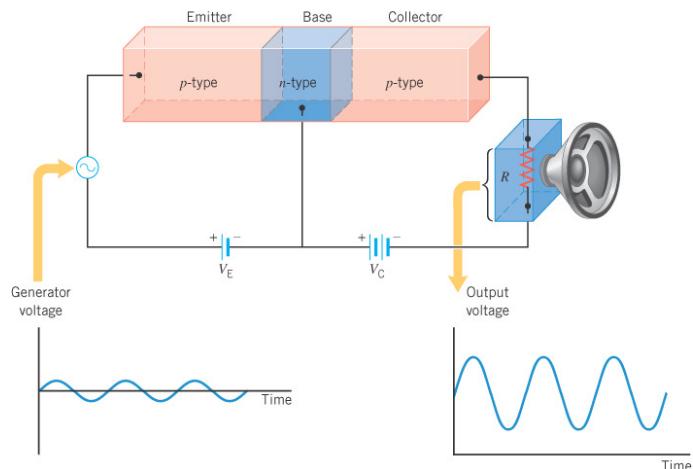
TRANSISTORS

A bipolar junction transistor can be used to amplify a smaller voltage into a larger one.



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